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CREEP-RUPTURE PROPERTIES OF UNALLOYED TANTALUM, Ta-10% W AND T-111 ALLOYS

R. L. Stephenson

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Ta-10% W AND T-111 ALLOYS

R. L. Stephenson

DECEMBER 1967

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CREEP-RUPTURE PROPERTIES OF UNALLOYED TANTALUM,
Ta-10% W AND T-111 ALLOYS

R. L. Stephenson

ABSTRACT

The long-time; high-temperature creep properties of unalloyed tantalum, Ta-10% W, and T-111 (Ta-8% W-2% Hf) were studied at 1204, 1427, and 1649°C (2200, 2600, and 3000°F). The Ta-10% W and T-111 were much stronger than unalloyed tantalum. The properties of Ta-10% W and T-111 were almost equal for the thermomechanical histories studied. The ductilities of all three materials were excellent.

INTRODUCTION

In recent years, increasing consideration has been given to tantalum-base alloys for high-temperature structural applications. On the basis of short-time data, the addition of 10% W appears to improve substantially the strength of tantalum.¹ This alloy also appears to have a low ductile-to-brittle transition temperature, improved oxidation resistance, good workability, and good weldability.^{1,2}

More recently, hafnium has been added to the binary alloy. This has resulted in the T-111 alloy (Ta-8% W-2% Hf) which also appears to have desirable ductility, weldability, and workability.²⁻⁴ In view of the potential strength offered by Ta-10% W and T-111 it was considered desirable to undertake a systematic study of their long-time (1000 hr) high-temperature creep properties. The creep properties of pure tantalum were also determined, primarily for comparative purposes.

¹M. L. Torti, "90 Ta-10 W Offers High Temperature Strength Plus Ductility," Space/Aeronautics 36, 87-93 (September 1961).

²G. G. Lessmann and D. R. Stoner, "Welding Refractory Metal for Space Power System Applications," paper presented at the 9th National SAMPLE Symposium on Joining of Materials for Aerospace Systems Nov. 15-17, 1965, Dayton, Ohio.

³R. G. Donnelly and G. M. Slaughter, "Weldability Evaluation of Advanced Refractory Alloys," Welding J. (N.Y.) 45, 250-s-257-s (June 1966).

⁴R. L. Ammon and R. T. Begley, Pilot Production and Evaluations of Tantalum Alloy Sheet, WANL-PR-M-0014 (June 1963).

MATERIALS

All materials used in this study were produced by National Research Corporation. Their compositions are shown in Tables 1, 2, and 3. All materials were tested in the cold worked condition.

Table 1. Vendor's Analysis of Unalloyed Tantalum, Heat 2202

Element	Weight Percent
Tungsten	0.004
Molybdenum	0.001
Titanium	0.0005
Copper	0.0001
Aluminum	0.0025
Niobium	0.0032
Silicon	0.0016
Nickel	0.0005
Chromium	< 0.0005
Iron	0.0010
Nitrogen	0.0020
Oxygen	0.0046
Carbon	0.0025
Tantalum	Balance

Table 2. Vendor's Analysis of Ta-10% W, Heat 1862

Element	Weight Percent
Tungsten	9.1
Molybdenum	< 0.0010
Nickel	< 0.0005
Chromium	< 0.0005
Iron	0.0010
Nickel	0.0023
Oxygen	0.0036
Carbon	0.0035
Tantalum	Balance

Table 3. Analyses of T-111 Alloy, Heat 2650

Element	Vendor's Analysis (wt %)	ORNL Analysis (wt %)
Tungsten	7.4	7.5
Hafnium	2.1	1.9
Carbon	0.0049	0.0070
Oxygen	0.0057	0.0053
Hydrogen		0.0004
Nitrogen	0.0023	0.0029
Tantalum	Balance	Balance

EXPERIMENTAL DETAILS

The apparatus used is described in a previous report.⁵ The tests were performed at pressures lower than 2×10^{-7} torr. Every test specimen was analyzed for interstitial impurities. The carbon contents of most specimens were less than 100 ppm after testing. The after-test oxygen content of most specimens was between 100 and 300 ppm. It was not possible to detect any systematic dependence of the mechanical properties on the posttest interstitial levels within the ranges mentioned. Sheet specimens 0.60 in. thick with a gage section 3×0.2 in. were used.

The metallographic specimens were prepared by vibratory polishing in a manner described by Long and Gray.⁶

RESULTS AND DISCUSSION

The creep-rupture properties of unalloyed tantalum at 1204°C (2200°F) are given in Fig. 1. Times to 1, 2, 5, and 10% creep are plotted as a function of stress along with the time to rupture. Similarly, the creep-rupture properties at 1427°C (2600°F) and 1649°C (3000°F) are given in

⁵R. L. Stephenson, Comparative Creep-Rupture Properties of D-43 and B-66 Alloys, ORNL-TM-944 (November 1964).

⁶E. L. Long, Jr., and R. J. Gray, Metals Progr. 74(4), 145-148 (October 1958).

Fig. 1. Creep-Rupture Properties of Unalloyed Tantalum at 1204°C (2200°F).

Figs. 2 and 3, respectively. Figure 4 gives the secondary creep rate as a function of stress for these three temperatures.

The creep-rupture properties of Ta-10% W alloy at 1204°C (2200°F) are shown in Fig. 5. Times to 1, 2, 5, and 10% creep are shown as a function of stress along with the time to rupture. Similarly, the creep-rupture

Fig. 2. Creep-Rupture Properties of Unalloyed Tantalum at 1427°C (2600°F).

Fig. 3. Creep-Rupture Properties of Unalloyed Tantalum at 1649°C (3000°F).

Fig. 4. Secondary Creep Rate vs Stress for Unalloyed Tantalum.

Fig. 5. Creep-Rupture Properties of Ta-10% W Alloy at 1204°C (2200°F).

properties at 1427°C (2600°F) and 1649°C (3000°F) are given in Figs. 6 and 7, respectively. The secondary creep rate is given as a function of stress for these three temperatures in Fig. 8.

Figure 9 gives the creep-rupture properties of T-111 at 1204°C (2200°F). Similar curves are given for T-111 at 1427°C (2600°F) and

Fig. 6. Creep-Rupture Properties of Ta-10% W Alloy at 1427°C (2600°F).

Fig. 7. Creep-Rupture Properties of Ta-10% W Alloy at 1649°C (3000°F).

Fig. 8. Secondary Creep Rate vs Stress for Ta-10% W Alloy.

Fig. 9. Creep-Rupture Properties of T-111 Alloy at 1204°C (2200°F).

1649°C (3000°F) in Figs. 10 and 11, respectively. Figure 12 gives the secondary creep rate as a function of stress at these temperatures.

The rupture elongation in percent is given in parentheses beside each point on the stress-rupture curves. In all three materials the ductilities are excellent.

Fig. 10. Creep-Rupture Properties of T-111 Alloy at 1427°C (2600°F).

Fig. 11. Creep-Rupture Properties of T-111 Alloy at 1649°C (3000°F).

Fig. 12. Secondary Creep Rate vs Stress for T-111 Alloy.

Figure 13 shows a photomicrograph of an unalloyed tantalum specimen with a rupture life of 27.5 hr at 1204°C (2200°F). It is clear that the material has recrystallized and attained a substantial grain size under these conditions. Specimens tested for longer times at correspondingly lower stresses frequently develop a pronounced substructure rather than a larger grain size. Figure 14 shows a microstructure typical of these specimens.

At 1427°C (2600°F), only a short time is required for the development of quite large grains in unalloyed tantalum. This is illustrated by the photomicrograph of a specimen with a rupture life of 7.0 hr at this temperature, shown in Fig. 15. Figure 16 shows the microstructure of a specimen tested at a stress which produced failure in 466.0 hr at 1427°C (2600°F). The microstructure is similar in appearance to the subgrains in Fig. 14, except that these small areas give the appearance of being

Fig. 13. Photomicrograph of Unalloyed Tantalum Specimen Which Failed After 27.5 hr at 6000 psi and 1204°C (2200°F). Etchant: $\text{NH}_4\text{-H}_2\text{O-HF}$. 100X.

Fig. 14. Photomicrograph of Unalloyed Tantalum Specimen Which Failed After 693.6 hr at 2750 psi and 1204°C (2200°F). 100X. Reduced 6%.

Fig. 15. Photomicrograph of Unalloyed Tantalum Specimen Which Failed After 7.0 hr at 3500 psi and 1427°C (2600°F). 100X.

Fig. 16. Photomicrograph of Unalloyed Tantalum Specimen Which Failed After 466.0 hr at 1500 psi and 1427°C (2600°F). 100x.

separated by high angle boundaries. At 1649°C (3000°F), very large grains are developed, as shown in Fig. 17. It is noteworthy that in no case are voids observed.

The microstructure of a Ta-10% W specimen which failed after 737.3 hr at 1204°C (2200°F) is shown in Fig. 18. Specimens tested at 1427°C (2600°F) and 1649°C (3000°F) are shown in Figs. 19 and 20, respectively. A slight tendency toward the formation of grain-boundary voids can be seen in Fig. 19, while very large grain-boundary voids are prominent in Fig. 20.

The microstructures of T-111 specimens tested at 1204, 1427, and 1649°C (2200, 2600, and 3000°F) are shown in Figs. 21, 22, and 23, respectively. The same increasing tendency for grain-boundary separation with increasing temperature is evident.

Upon comparison of creep-rupture data presented here, it is apparent that the addition of 10% W has a pronounced effect on the strength. The further addition of 2% Hf, however, has had little effect for the material histories examined here. Since precipitates too large to contribute to dispersion strengthening are observed (Fig. 23), it is possible that a heat treatment which places these in solution and reprecipitates them in a more finely dispersed state may produce an improvement of T-111 over Ta-10% W.

Fig. 17. Photomicrograph of Unalloyed Tantalum Specimen Which Failed After 374.9 hr at 650 psi and 1649°C (3000°F). 100X.

Fig. 18. Photomicrograph of Ta-10% W Specimen Which Failed After 737.3 hr at 17,000 psi and 1204°C (2200°F). Etchant: 25 HF-25 HNO₃-5 glycerin. 100X.

Fig. 19. Photomicrograph of Ta-10% W Specimen Which Failed After 441.8 hr at 9000 psi and 1427°C (2600°F). 100X.

Fig. 20. Photomicrograph of Ta-10% W Specimen Which Failed After 270.6 hr at 4500 psi and 1649°C (3000°F). 100X.

Fig. 21. Photomicrograph of T-111 Alloy Specimen Which Failed After 975.1 hr at 17,500 psi and 1204°C (2200°F). Etchant: $\text{H}_2\text{O}-\text{HF}-\text{NH}_4\text{OH}-\text{H}_2\text{SO}_4$. 100X.

Fig. 22. Photomicrograph of T-111 Alloy Specimen Which Failed After 575.4 hr at 7500 psi and 1427°C (2600°F). 100X.

Fig. 23. Photomicrograph of T-111 Alloy Specimen Which Failed After 493.2 hr at 3500 psi and 1649°C (3000°F). 100X.

The microstructures of the unalloyed tantalum appear very clean; those of the Ta-10% alloy show only a slight indication of a precipitate while precipitates are distinctly visible in the T-111 alloy microstructures. Grain growth is much faster in tantalum than in Ta-10% W or T-111. Grain growth appears to be slightly greater in Ta-10% W than in T-111 at 1427 and 1649°C (2600 and 3000°F). The precipitates in T-111 are probably HfC and HfO₂ and may be responsible for the additional grain-growth inhibition.

SUMMARY AND CONCLUSIONS

The creep-rupture properties of cold worked tantalum, Ta-10% W, and T-111 (Ta-8% W-2% Hf) at 1204, 1427, and 1649°C (2200, 2600, and 3000°F) are presented. It is apparent from these data that substantial solution strengthening is derived from the addition of tungsten to tantalum. No further strengthening was observed upon the addition of

hafnium to this binary alloy for the material conditions investigated. However, some additional grain-size stabilization was noted in the T-111, possibly due to hafnium-base precipitates in the microstructure.

Good rupture ductilities were observed in all cases.

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